Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material:	
Metal	
Overall Length:	
0.190 inches	
Terminal Length:	
0.500 inches	
Overall Diameter:	
0.219 inches	
Component Name And	Quantity:
2 transistor	
Mounting Method:	
Terminal	
Features Provided:	
Hermetically sealed case	
Semiconductor Materia	I:
Silicon all transistor	
Voltage Rating In Volts	Per Characteristic:
40.0 breakdown voltage,	gate-to-source, with all other terminals short-circuited to source all transistor
Current Rating Per Cha	racteristic:
1.00 milliamperes zero-g	ate-voltage drain current all transistor and 8.00 milliamperes zero-gate-voltage drain current all transistor
Power Rating Per Chara	acteristic:
300.0 milliwatts total dev	ice dissipation all transistor
Terminal Type And Qua	ntity:
6 uninsulated wire lead	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	